



FEATURES

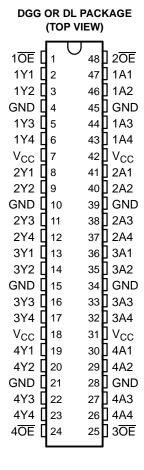
- Member of the Texas Instruments Widebus™
 Family
- EPIC[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- Output Ports Have Equivalent 26-Ω Series Resistors, So No External Resistors Are Required
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

NOTE: For tape-and-reel order entry, the DGGR package is abbreviated to GR.

DESCRIPTION

This 16-bit buffer/driver is designed for 1.65-V to 3.6-V $V_{\rm CC}$ operation.

The SN74ALVCH162244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters.



The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. It provides true outputs and symmetrical active-low output-enable (OE) inputs.

The outputs, which are designed to sink up to 12 mA, include equivalent 26- Ω resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH162244 is characterized for operation from -40°C to 85°C.

FUNCTION TABLE (each 4-bit buffer)

INPL	JTS	OUTPUT
ŌĒ	Α	Υ
L	Н	Н
L	L	L
Н	Χ	Z

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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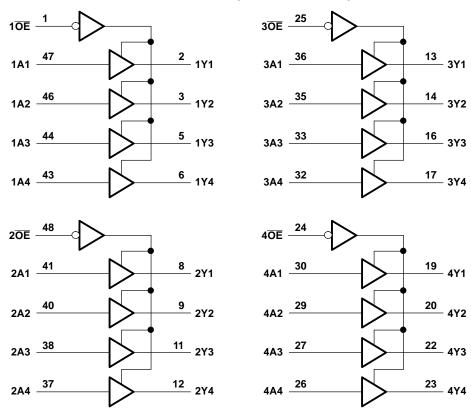


LOGIC SYMBOL(1) 1 10E EN1 48 2OE EN2 25 EN3 3OE 24 4OE EN4 47 2 1 ▽ 1Y1 1A1 1 3 46 1Y2 1A2 44 5 1Y3 1A3 43 6 1Y4 1A4 41 8 2 ▽ 2A1 1 2Y1 40 9 2Y2 2A2 38 11 2A3 2Y3 37 12 2Y4 2A4 36 13 3 ▽ 3Y1 3A1 35 14 3A2 3Y2 33 16 3Y3 3A3 17 32 3A4 3Y4 30 19 4 ▽ 1 4Y1 4A1 29 20 4A2 **4Y2** 27 22 4A3 4Y3 26 23 4Y4 4A4

(1) This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.



LOGIC DIAGRAM (POSITIVE LOGIC)



ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	4.6	V
VI	Input voltage range (2)		-0.5	4.6	V
Vo	Output voltage range ⁽²⁾⁽³⁾		-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V _I < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through each V _{CC} or GND			±100	mA
0	Dockoro thermal impedence (4)	DGG package		89	°C/M
θ_{JA}	Package thermal impedance ⁽⁴⁾	DL package		94	°C/W
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(3) This value is limited to 4.6 V maximum.

⁽⁴⁾ The package thermal impedance is calculated in accordance with JESD 51.

SCES065F-JANUARY 1996-REVISED OCTOBER 2004



RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		1.65	3.6	V	
		V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}			
V_{IH}	High-level input voltage	V _{CC} = 2.3 V to 2.7 V	1.7		V	
		V _{CC} = 2.7 V to 3.6 V	2			
		V _{CC} = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
V_{IL}	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		
V _I	Input voltage		0	V_{CC}	V	
Vo	Output voltage		0	V_{CC}	V	
		V _{CC} = 1.65 V		-2		
	LP-de la collection de comment	V _{CC} = 2.3 V		-6	~ ∧	
I _{OH}	High-level output current	$V_{CC} = 2.7 \text{ V}$		-8	mA	
		V _{CC} = 3 V		-12		
		V _{CC} = 1.65 V		2		
	Low level output ourrent	V _{CC} = 2.3 V		6	mA	
l _{OL}	Low-level output current	$V_{CC} = 2.7 \text{ V}$		8	mA	
		V _{CC} = 3 V		12		
Δt/Δν	Input transition rise or fall rate			10	ns/V	
T _A	Operating free-air temperature		-40	85	°C	

⁽¹⁾ All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



SN74ALVCH162244 WITH 3-STATE OUTPUTS

ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

PAF	RAMETER	TEST CO	ONDITIONS	V _{cc}	MIN	TYP ⁽¹⁾	MAX	UNIT	
		I _{OH} = -100 μA		1.65 V to 3.6 V	V _{CC} - 0.2				
		I _{OH} = -2 mA		1.65 V	1.2				
		I _{OH} = -4 mA		2.3 V	1.9				
V_{OH}		L C A		2.3 V	1.7			V	
		$I_{OH} = -6 \text{ mA}$		3 V	2.4				
		I _{OH} = -8 mA		2.7 V	2				
		I _{OH} = -12 mA	3 V	2					
		I _{OL} = 100 μA		1.65 V to 3.6 V			0.2		
		I _{OL} = 2 mA		1.65 V			0.45		
		I _{OL} = 4 mA		2.3 V			0.4		
V_{OL}				2.3 V			0.55	V	
		$I_{OL} = 6 \text{ mA}$		3 V			0.55		
		I _{OL} = 8 mA		2.7 V			0.6		
		I _{OL} = 12 mA	3 V			0.8			
I _I		$V_I = V_{CC}$ or GND		3.6 V			±5	μΑ	
		V _I = 0.58 V		1.65 V	25				
		V _I = 1.07 V		1.65 V	-25				
		V _I = 0.7 V		2.3 V	45				
I _{I(hold)}		V _I = 1.7 V		2.3 V	-45			μΑ	
		V _I = 0.8 V		3 V	75				
		V _I = 2 V		3 V	-75				
		$V_I = 0$ to 3.6 $V^{(2)}$		3.6 V			±500		
l _{OZ}		$V_O = V_{CC}$ or GND		3.6 V			±10	μΑ	
I _{CC}		$V_I = V_{CC}$ or GND,	I _O = 0	3.6 V			40	μΑ	
ΔI_{CC}		One input at V _{CC} - 0.6 V,	Other inputs at V _{CC} or GND	3 V to 3.6 V			750	μΑ	
	Control inputs	V V or CND		221/		3		~F	
C _i	Data inputs	$V_I = V_{CC}$ or GND		3.3 V		6		pF	
Co	Outputs	$V_O = V_{CC}$ or GND		3.3 V		7		pF	

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1 through Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 1.8 V	V _{CC} = 2 ± 0.2	2.5 V 2 V	V _{CC} =	2.7 V	V _{CC} = 3 ± 0.3	3.3 V 3 V	UNIT
	(INFOT)	(001701)	TYP	MIN	MAX	MIN	MAX	MIN	MAX	
t _{pd}	A	Υ	(1)	1	4.9		4.7	1	4.2	ns
t _{en}	ŌĒ	Υ	(1)	1	6.8		6.7	1	5.6	ns
t _{dis}	ŌĒ	Υ	(1)	1	6.3		5.7	1	5.5	ns

⁽¹⁾ This information was not available at the time of publication.

All typical values are at $V_{CC} = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$. This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

SN74ALVCH162244 16-BIT BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES065F-JANUARY 1996-REVISED OCTOBER 2004



OPERATING CHARACTERISTICS

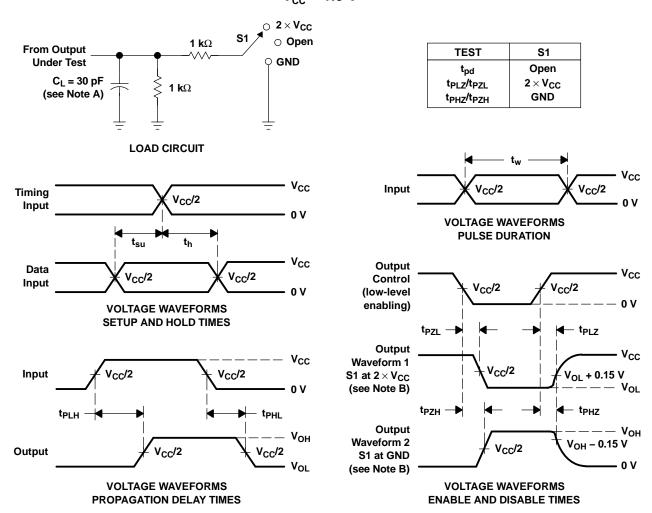
 $T_A = 25^{\circ}C$

	PARAMETER		TEST CONDITIONS	V_{CC} = 1.8 V	$V_{CC} = 2.5 \text{ V}$	V _{CC} = 3.3 V	UNIT	
				TYP	TYP	TYP		
_	Dower dissination conseitance	Outputs enabled	$C_1 = 50 \text{ pF}, f = 10 \text{ MHz}$	(1)	16	19	ρF	
Cpd	Power dissipation capacitance	Outputs disabled	$O_L = 50 \text{ pr}, I = 10 \text{ M/Hz}$	(1)	4	5	þΓ	

(1) This information was not available at the time of publication.



PARAMETER MEASUREMENT INFORMATION $V_{cc} = 1.8 \text{ V}$



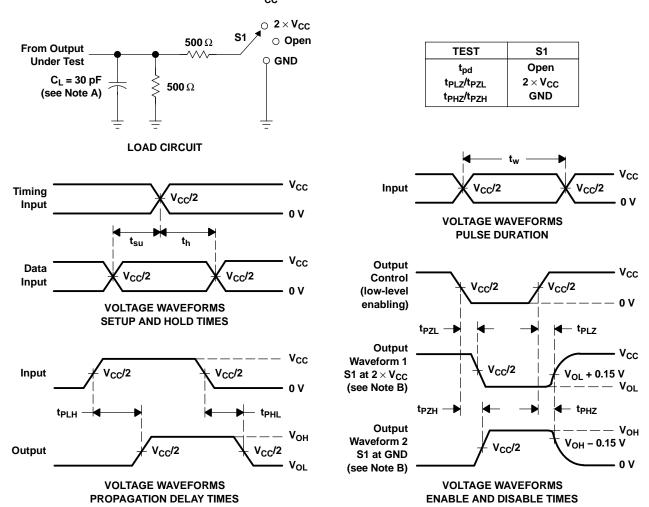
NOTES: A. C₁ includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z $_{O}$ = 50 Ω , t_{f} \leq 2 ns, t_{f} \leq 2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{Pl 7} and t_{PH7} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 1. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.5 V \pm 0.2 V



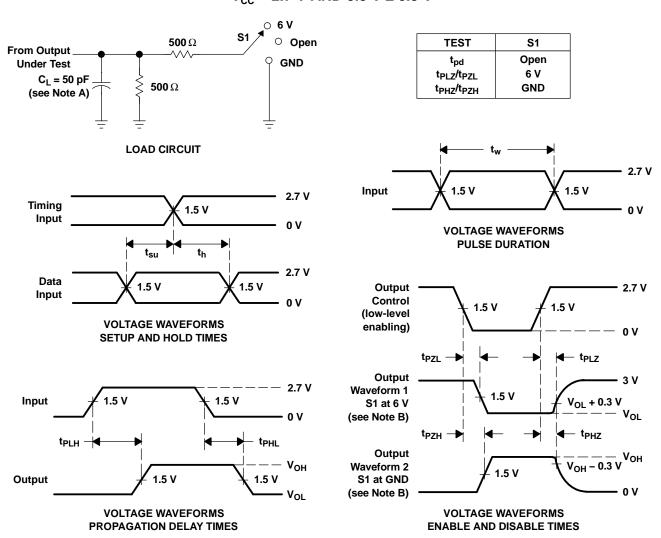
NOTES: A. C₁ includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 $\Omega,\,t_{f}$ \leq 2 ns, t_{f} \leq 2 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PL7} and t_{PH7} are the same as t_{dis}.
- F. t_{PZL} and t_{PZH} are the same as t_{en}.
- G. t_{PLH} and t_{PHL} are the same as t_{pd}.

Figure 2. Load Circuit and Voltage Waveforms



PARAMETER MEASUREMENT INFORMATION V_{CC} = 2.7 V AND 3.3 V \pm 0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{f} \leq$ 2.5 ns. $t_{f} \leq$ 2.5 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 3. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM

10-Dec-2020

PACKAGING INFORMATION

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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
74ALVCH162244GRG4	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162244	Samples
SN74ALVCH162244DGG	ACTIVE	TSSOP	DGG	48	40	RoHS & Green	NIPDAU	Level-1-260C-UNLIM		ALVCH162244	Samples
SN74ALVCH162244DL	ACTIVE	SSOP	DL	48	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162244	Samples
SN74ALVCH162244DLR	ACTIVE	SSOP	DL	48	1000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162244	Samples
SN74ALVCH162244GR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVCH162244	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

10-Dec-2020

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVCH162244DLR	SSOP	DL	48	1000	330.0	32.4	11.35	16.2	3.1	16.0	32.0	Q1
SN74ALVCH162244GR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVCH162244DLR	SSOP	DL	48	1000	367.0	367.0	55.0
SN74ALVCH162244GR	TSSOP	DGG	48	2000	367.0	367.0	45.0

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

PowerPAD is a trademark of Texas Instruments.





SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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